

30V P-Channel Power MOSFET



SOP-8



Pin Definition:

1. Source 8. Drain
2. Source 7. Drain
3. Source 6. Drain
4. Gate 5. Drain

Key Parameter Performance

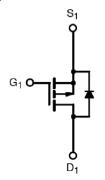
| Parameter | | Value | Unit | |
|---------------------------|------------------------|-------|------|--|
| V_{DS} | | -30 | V | |
| R _{DS(on)} (max) | V _{GS} =-10V | 60 | | |
| | V _{GS} =-4.5V | 90 | mΩ | |
| Q_g | | 5.1 | nC | |

Ordering Information

| Part No. | Package | Packing | | |
|-----------------|---------|-------------------|--|--|
| TSM600P03CS RLG | SOP-8 | 2.5kps / 13" Reel | | |

Note: "G" denotes for Halogen- and Antimony-free as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds

Block Diagram



P-Channel MOSFET

Absolute Maximum Ratings (Tc = 25°C unless otherwise noted)

| Parameter | | Symbol | Limit | Unit |
|--|--------------------|-----------------------------------|-------------|------|
| Drain-Source Voltage | | V_{DS} | -30 | V |
| Gate-Source Voltage | | V_{GS} | ±20 | V |
| Continuous Drain Current* | $Tc = 25^{\circ}C$ | | -4.7 | Α |
| | Tc = 100°C | I _D | -3 | Α |
| Pulsed Drain Current (Note 1) | | I _{DM} | -18.8 | Α |
| Power Dissipation @ T _C = 25°C | | P _D | 2.1 | W |
| Operating Junction and Storage Temperature Range | | T _J , T _{STG} | -55 to +150 | °C |

Thermal Performance

| Parameter | Symbol | Limit | Unit |
|--|------------------|-------|------|
| Thermal Resistance - Junction to Ambient | R _{eJA} | 50 | °C/W |

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Electrical Specifications (T_J = 25°C unless otherwise noted)

| Parameter | Conditions | Symbol | Min | Тур | Max | Unit |
|-----------------------------------|---|---------------------|------|------|-------|------|
| Static | | | | | | |
| Drain-Source Breakdown Voltage | $V_{GS} = 0V, I_D = 250\mu A$ | BV_{DSS} | -30 | | | V |
| Drain-Source On-State Resistance | $V_{GS} = -10V, I_D = -3A$ | R _{DS(ON)} | 1 | 44 | 60 | mΩ |
| | $V_{GS} = -4.5V, I_D = -2A$ | | | 73 | 90 | |
| Gate Threshold Voltage | $V_{DS} = V_{GS}, I_{D} = 250 \mu A$ | $V_{GS(TH)}$ | -1.2 | -1.6 | -2.5 | V |
| Zero Gate Voltage Drain Current | $V_{DS} = -30V, T_{J} = 25^{\circ}C$ | I _{DSS} | | | -1 | μA |
| | $V_{DS} = -24V, T_{J} = 125^{\circ}C$ | | | | -10 | |
| Gate Body Leakage | $V_{GS} = \pm 20V, V_{DS} = 0V$ | I_{GSS} | | | ±100 | nA |
| Forward Transconductance (Note 2) | $V_{DS} = -10V, I_{D} = -3A$ | g _{fs} | | 3.5 | | S |
| Dynamic | | | | | | |
| Total Gate Charge (Note 2,3) | \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ | Q_g | - | 5.1 | | nC |
| Gate-Source Charge (Note 2,3) | $V_{DS} = -15V, I_D = -3A,$ $V_{GS} = -4.5V$ | Q_gs | 1 | 2 | | |
| Gate-Drain Charge (Note 2,3) | $v_{GS} = -4.5v$ | Q_gd | 1 | 2.2 | | |
| Input Capacitance | $V_{DS} = -15V, V_{GS} = 0V,$ | C_{iss} | | 560 | | pF |
| Output Capacitance | | C_{oss} | | 55 | | |
| Reverse Transfer Capacitance | f = 1.0MHz | C_{rss} | | 40 | | |
| Switching | | | | | | |
| Turn-On Delay Time (Note 2,3) | | $t_{d(on)}$ | 1 | 3.4 | | |
| Turn-On Rise Time (Note 2,3) | $V_{DD} = -15V, I_{D} = -1A,$ | t _r | 1 | 10.8 | | ns |
| Turn-Off Delay Time (Note 2,3) | $V_{GS} = -10V, R_G = 6\Omega$ | $t_{d(off)}$ | 1 | 26.9 | | |
| Turn-Off Fall Time (Note 2,3) | | t _f | | 6.9 | | |
| Source-Drain Diode Ratings and Ch | aracteristic | | | | | |
| Maximum Continuous Drain-Source | | 1 | | | 4.7 | ^ |
| Diode Forward Current | Integral reverse diode in | I _S | | | -4.7 | Α |
| Maximum Pulse Drain-Source Diode | the MOSFET | I _{SM} | | | -18.8 | А |
| Forward Current | | | | | | |
| Diode-Source Forward Voltage | $V_{GS} = 0V, I_{S} = -1A$ | V_{SD} | | | -1 | V |

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Note:

- 1. Pulse width limited by safe operating area
- 2. Pulse test: pulse width ≤300µs, duty cycle ≤2%
- 3. Switching time is essentially independent of operating temperature.

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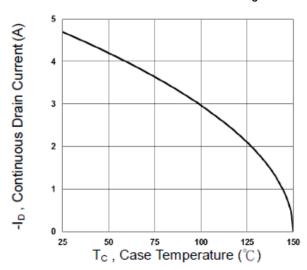


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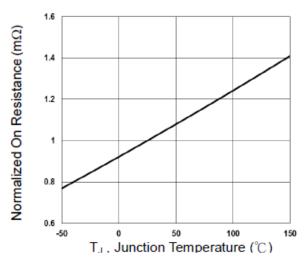


Electrical Characteristics Curve

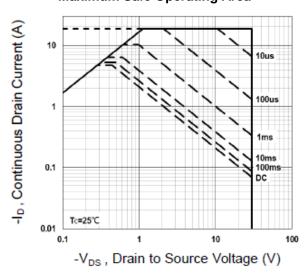
Continuous Drain Current vs. Tc



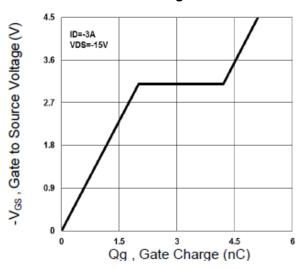
On-Resistance vs. Junction Temperature



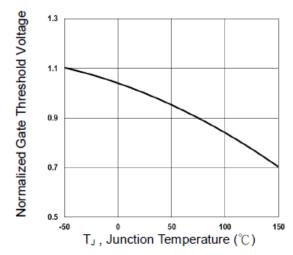
Maximum Safe Operating Area



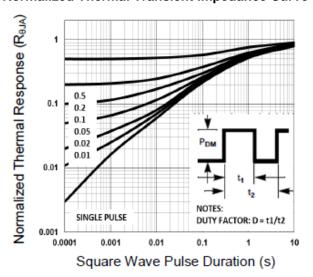
Gate Charge



Threshold Voltage vs. Junction Temperature



Normalized Thermal Transient Impedance Curve



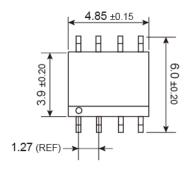
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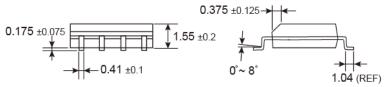


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SOP-8 Mechanical Drawing





Unit: Millimeters

MARKING DIAGRAM



Y = Year Code

M = Month Code for Halogen Free Product (O=Jan, P=Feb, Q=Mar, R=Apl, S=May, T=Jun, U=Jul, V=Aug, W=Sep, X=Oct, Y=Nov, Z=Dec)

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L = Lot Code

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TSM600P03CS 30V P-Channel Power MOSFET



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